SN74ALVCH16836 20-BIT UNIVERSAL BUS DRIVER WITH 3-STATE OUTPUTS

SCES089C - OCTOBER 1996 - REVISED FEBRUARY 1999

•	Member of the Texas Instruments
	<i>Widebus</i> ™ Family

- EPIC[™] (Enhanced-Performance Implanted CMOS) Submicron Process
- Designed to Comply With JEDEC 168-Pin and 200-Pin SDRAM Buffered DIMM Specification
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages

description

This 20-bit universal bus driver is designed for 1.65-V to 3.6-V $\rm V_{CC}$ operation.

Data flow from A to Y is controlled by the output-enable (\overline{OE}) input. The device operates in the transparent mode when the latch-enable (\overline{LE}) input is low. The A data is latched if the clock (CLK) input is held at a high or low logic level. If \overline{LE} is high, the A data is stored in the latch/flip-flop on the low-to-high transition of CLK. When \overline{OE} is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74ALVCH16836 is characterized for operation from -40° C to 85° C.

DGG OR DL PACKAGE (TOP VIEW) OE 1 56 CLK Y1 2 55 A1 Y2 3 54 A2 GND 4 53 GND Y3 5 52 A3 Y4 6 51 A4 VCC 7 50 VCC Y5 8 49 A5 Y6 9 48 A6 Y7 10 47 A7 GND 11 46 GND Y8 12 45 A8 Y9 13 44 A9 Y10 14 43 A10 Y11 15 42 A11 Y12 16 41 A12 Y13 17 40 A13 GND 18 39 GND Y14 19 38 A14 Y15 20 37 A15					
	(TC	P VI	EW)		
OE		υ	56	ПСІК	
	2		55	E	
	3				
			53	GND	
			52	АЗ	
			51	A4	
V _{CC}	7		50	Vcc	
	8		49	A5	
Y6	9		48	A6	
GND	11		46	GND	
Y8	12		45	A8	
				P -	
Y10	14			F	
				F	
	17				
	-				
	19			E	
	20			E	
Y16	21			A16	
V _{CC}	22		35	Vcc	
Y17	23		34	2	
Y18				A18	
GND	25		32	GND	
Y19	26			A19	
Y20	27		30	A20	
NC	28		29	μle	

NC - No internal connection



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FUNCTION TABLE

	INP	UTS		OUTPUT						
OE	LE	CLK	Α	Y						
Н	Х	Х	Х	Z						
L	L	Х	L	L						
L	L	Х	Н	н						
L	Н	\uparrow	L	L						
L	Н	\uparrow	Н	н						
L	Н	н	Х	Y0 [†]						
L	Н	L	Х	Y0‡						

[†]Output level before the indicated steady-state input conditions were established, provided that CLK is high before $\overline{\text{LE}}$ goes low

[‡]Output level before the indicated steady-state input conditions were established

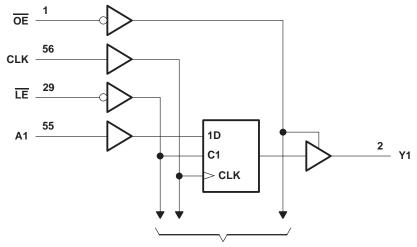
logic symbol§

OE CLK LE	1 56 29 2	EN1 > 2C3 C3 G2	1	3 D	55	Α1
	3	1 V		30	54	
Y2	5				52	A2
Y3	6				51	A3
Y4	8				49	A4
Y5	9				48	A5
Y6	10				47	A6
Y7	12				45	A7
Y8 Y9	13				44	A8
Y10	14				43	A9 A10
Y11	15				42	
Y12	16				41	A11 A12
Y12	17				40	
Y14	19				38	A13
Y15	20				37	A14 A15
Y16	21				36	A15
Y17	23				34	A10
Y18	24				33	A17
Y19	26				31	A16
Y20	27				30	A20

§ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



logic diagram (positive logic)



To 19 Other Channels

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC} Input voltage range, V_I (see Note 1) Output voltage range, V_O (see Notes 1 and 2) Input clamp current, I_{IK} ($V_I < 0$) Output clamp current, I_{OK} ($V_O < 0$) Continuous output current, I_O Continuous current through each V_{CC} or GND Package thermal impedance, θ_{IA} (see Note 3): DGG package	0.5 V to 4.6 V 5 V to V _{CC} + 0.5 V 50 mA 50 mA ±50 mA ±100 mA
DL package	74°C/W
Storage temperature range, T _{stg}	

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. This value is limited to 4.6 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51.



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recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
Vcc	Supply voltage		1.65	3.6	V	
		V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$			
VIH	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2			
		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		
VIL	Low-level input voltage	V_{CC} = 2.3 V to 2.7 V		0.7	V	
		$V_{CC} = 2.7 V \text{ to } 3.6 V$		0.8		
VI	Input voltage		0	VCC	V	
Vo	Output voltage		0	VCC	V	
		V _{CC} = 1.65 V		-4		
		V _{CC} = 2.3 V		-12	12 mA	
ЮН	High-level output current	$V_{CC} = 2.7 V$		-12		
		V _{CC} = 3 V		-24		
		V _{CC} = 1.65 V		4		
1		V _{CC} = 2.3 V		12		
IOL	Low-level output current	V _{CC} = 2.7 V		12	2 mA	
		V _{CC} = 3 V		24		
$\Delta t / \Delta v$	Input transition rise or fall rate			10	ns/V	
ТА	Operating free-air temperature		-40	85	°C	

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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PA	RAMETER	TEST CO	ONDITIONS	V _{CC}	MIN	TYP†	MAX	UNIT	
		I _{OH} = –100 μA		1.65 V to 3.6 V	V _{CC} -0.	2			
		I _{OH} = -4 mA		1.65 V	1.2				
		I _{OH} = -6 mA		2.3 V	2				
∨он				2.3 V	1.7			V	
		I _{OH} = -12 mA		2.7 V	2.2				
				3 V	2.4				
VOL II II(hold) IOZ ICC ΔICC Citrol inputs	I _{OH} = -24 mA		3 V	2					
		I _{OL} = 100 μA		1.65 V to 3.6 V			0.2		
		I _{OL} = 4 mA		1.65 V			0.45		
		I _{OL} = 6 mA		2.3 V			0.4	V	
VOL		1	2.3 V			0.7	V		
	V _{OL}	I _{OL} = 12 mA		2.7 V			0.4		
II		I _{OL} = 24 mA		3 V			0.55		
Ц		$V_I = V_{CC}$ or GND		3.6 V			±5	μΑ	
		V _I = 0.58 V	1.65 V	25					
		V _I = 1.07 V		1.65 V	-25				
		V _I = 0.7 V		2.3 V	45				
II(hold)		V _I = 1.7 V		2.3 V	-45			μA	
		V _I = 0.8 V		3 V	75				
		V _I = 2 V		3 V	-75				
		V _I = 0 to 3.6 V [‡]		3.6 V			±500		
IOZ		V _O = V _{CC} or GND		3.6 V			±10	μΑ	
ICC		$V_{I} = V_{CC}$ or GND,	IO = 0	3.6 V			40	μA	
		One input at V _{CC} – 0.6 V,	Other inputs at V_{CC} or GND	3 V to 3.6 V			750	μA	
	Control inputs			2.2.1/				- F	
	Data inputs	$V_{I} = V_{CC}$ or GND		3.3 V				pF	
Co	Outputs	V _O = V _{CC} or GND		3.3 V				pF	

electrical characteristics	over	recommended	operating	free-air	temperature	range	(unless
otherwise noted)					-	•	

[†] All typical values are at V_{CC} = 3.3 V, T_A = 25° C.

[‡] This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.



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timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figures 1 through 3)

				V _{CC} =	1.8 V	۲ <mark>0.2</mark> × 0.2		V _{CC} =	2.7 V	۲ <mark>0.5 v_{cc} =</mark>	3.3 V 3 V	UNIT
				MIN	MIN MAX		MAX	MIN	MAX	MIN	MAX	
fclock	Clock freque	ency	су									MHz
	Pulse duration	LE low										ns
tw		CLK high or low										115
		Data before CLK↑										
t _{su}	Setup time		CLK high									ns
		Data before LE↑	CLK low									
4		Data after CLK↑	-									
^t h	Hold time	Data after LE↑	CLK high or low									ns

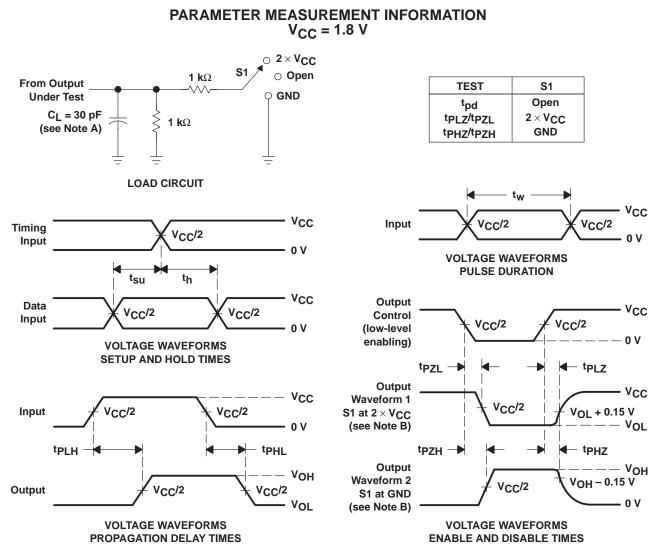
switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

PARAMETER	FROM TO (INPUT) (OUTPUT)			-	V _{CC} =	1.8 V	= ۷ _{CC} ± 0.2	2.5 V 2 V	V _{CC} =	2.7 V	V _{CC} = ± 0.3	3.3 V 3 V	UNIT
		MIN	TYP	MIN	MAX	MIN	MAX	MIN	MAX				
fmax											MHz		
	A												
^t pd	LE	Y									ns		
	CLK												
ten	OE	Y									ns		
^t dis	ŌE	Y									ns		

operating characteristics, $T_A = 25^{\circ}C$

PARAMETER			TEST CO	NDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	UNIT
<u> </u>	Power dissipation	Outputs enabled	$C_{1} = 0.$	f = 10 MHz				ρF
Cpd	capacitance	Outputs disabled	$C_{L} = 0,$	T = TU MHZ				

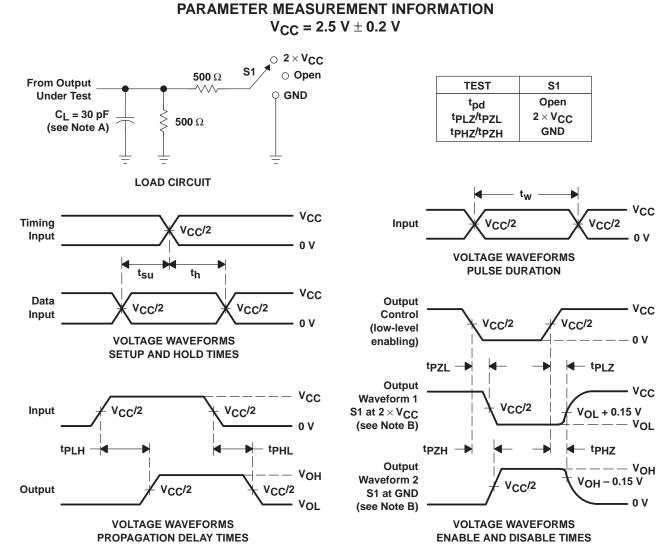




- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2 ns, t_f \leq 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tPLH and tPHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

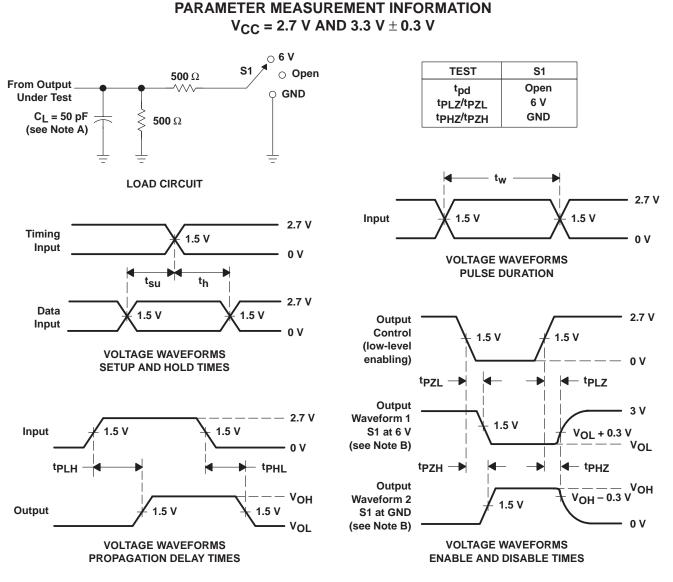




- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_Q = 50 Ω, t_f ≤ 2 ns, t_f ≤ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

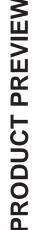
Figure 2. Load Circuit and Voltage Waveforms





- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
 Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
 - F. tPZL and tPZH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.







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